



## WEST Search History

DATE: Monday, October 18, 2004

### Hide? Set Name Query

### Hit Count

*DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ*

<input type="checkbox"/>	L8	l2 and l6	12
<input type="checkbox"/>	L7	l1 and L6	5
<input type="checkbox"/>	L6	deep junction	880
<input type="checkbox"/>	L5	l1 and L4	1
<input type="checkbox"/>	L4	(spaced or spaced apart) near3 ((insulator or insulating) bodies)	369
<input type="checkbox"/>	L3	l1 and l2	1
<input type="checkbox"/>	L2	((insulator or insulation or insulating or dielectric or oxide) (layer or film)) same (second thickness)	1331
<input type="checkbox"/>	L1	MOSgated or MOS gated or metal oxide semiconductor gated or metal oxide silicon gated	720

END OF SEARCH HISTORY

10/18/2004 Craig A. Thompson

## ePHOENIX Reference Manager

Application Number:

**No Forms Found for Application Number 10/644,306**

10-18-04

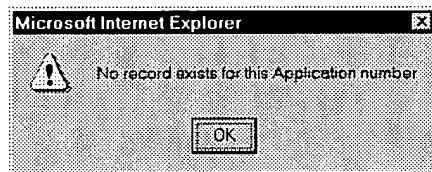
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# Electronic Information Disclosure Statement

## US Document Identifiers Search Page

Application Number 10644306

SEARCH



10-18-04

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